

IGBT Module

Features

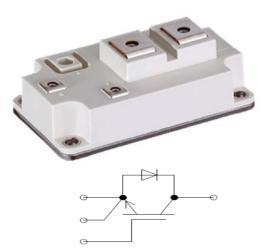
- ■1200V 600A,VCE(sat)(typ.) = 3.0 V
- Ultrafast switching speed
- Excellent short circuit ruggednesss
- 62mm Single tube module

Mechanical Data

- Case: D2(6 2mm)(plastic package). Lead free; RoHS compliant
- Molding Compound Flammability Rating: UL 94 V-0



- Inverter for motor drive
- AC and DC servo drive amplifier
- Excellent Current Sharing in Parallel Operation



Equivalent Circuit Schematic

Applications

CREATEK's IGBTs offer lower losses and higher energy for application such as motor drive ,UPS, inverter and other soft switching applications.

Absolute Maximum Ratings of IGBT

Symbol	Parameter	Value	Units	
V_{CES}	Collector to Emitter Voltage	1200	V	
V_{GES}	Continuous Gate to Emitter Voltage		±30	V
	Continuous Collector Current	T _C = 25°C	1200	Δ.
I _C	Continuous Collector Current	T _C = 100°C	600	А
I _{CM}	Pulse Collector Current T _J = 150°C		1200	А
P_D	Maximum Power Dissipation (IGBT) $T_C = 25^{\circ}C$, $T_J = 150^{\circ}C$		2660	W
t _{sc}	Short Circuit Withstand Time	> 10	μs	
T_J	Maximum IGBT Junction Temperature	150	°C	
T_JOP	Maximum Operating Junction Temperature Ran	-40 to +150	°C	
T _{stg}	Storage Temperature Range	-40 to +125	°C	

Absolute Maximum Ratings of Freewheeling Diode

Symbol	Parameter	Value	Units	
V_{RRM}	Repetitive Peak Reverse Voltage Preliminary Dat	1200	٧	
	Diode Continuous Forward Current	T _C = 25°C	1200	
l _F	Diode Continuous Forward Current	T _C = 100°C	600	A
I _{FM}	Diode Maximum Forward Current		1200	А

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Electrical Characteristics of IGBT(Tj=25°C unless otherwise noted)

Symbol	Parameter	Parameter TestConditions		Min.	Тур.	Max.	Units
BV _{CES}	Collector to Emitter Breakdown Voltage	V _{GE} = 0V, I _C = 1mA		1200			V
I _{CES}	Collector to Emitter Leakage Current	$V_{GE} = 0V, V_{CE} = V_{CES}$				5	mA
I _{GES}	Gate to Emitter Leakage Current	$V_{GE} = \pm 30V$, $V_{CE} = 0V$				400	nA
V _{GE(th)}	Gate Threshold Voltage	I _C = 1mA, V _{CE} = V _{GE}		4.5		5.7	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage (Module Level)	$I_{C} = 600A,$ $V_{GE} = 15V$ $T_{J} = 25^{\circ}C$ $T_{J} = 125^{\circ}C$	T _J = 25°C		3.00	3.20	V
				3.60		V	

Electrical Characteristics of IGBT(Tj=25°C unless otherwise noted)

Symbol	Parameter	TestCon	ditions	Min.	Тур.	Max.	Units			
	t _{d(on)} Turn-on Delay Time		T _J = 25°C		140					
^L d(on)			T _J = 125°C		150		ns			
			T _J = 25°C		120		20			
t _r	Turn-on Rise Time		T _J = 125°C		125		ns			
4	Turn off Dolov Time		T _J = 25°C		870		no			
$t_{d(off)}$	Turn-off Delay Time	V _{CC} = 600V	T _J = 125°C		920		ns			
4	t_{f} Turn-off Fall Time V_{G}	$I_{C} = 600A$ $R_{G} = 1.1\Omega$ $V_{GE} = \pm 15V$	T _J = 25°C		120		no			
Lf		Inductive Load	T _J = 125°C		135		ns			
Е	Turn on Switching Long		T _J = 25°C		15.5		mJ			
E _{on}	Turn-on Switching Loss		T _J = 125°C		25.0		IIIJ			
Е	Turn off Outstablish Land	E _{off} Turn-off Switching Loss	E Turn off Switching Loss	E _{off} Turn-off Switching Loss		T _J = 25°C		43.0		m.l
⊏off	rum-on Switching Loss		T _J = 125°C		52.5		mJ			
Q_g	Total Gate Charge		T _J = 25°C		5000		nC			
R _{gint}	Integrated gate resistor	f = 1M; Vpp = 1V	T _J = 25°C		1.3		Ω			
C _{ies}	Input Capacitance	V _{CE} = 25V V _{GE} = 0V f = 1MHz	T _J = 25°C		50					
C _{oes}	Output Capacitance		T _J = 25°C		7.0		nF			
C _{res}	Reverse Transfer Capacitance		T _J = 25°C		4.0					
R _{eJC}	Thermal Resistance, Junction-to-Case (IGBT)					0.047	°C/W			



Electrical and Switching Characteristics of Freewheeling Diode

Symbol	Parameter	TestConditions		Min.	Тур.	Max.	Units	
	Diode Forward Voltage	I _F = 600A ,	T _J = 25°C		1.90	2.20	V	
V_{F}	V _F Blode Follward Voltage	V _{GE} = 0V	T _J = 125°C		1.90		V	
+	t _{rr} Diode Reverse Recovery Time		T _J = 25°C		230		ns	
ч _{гг}			T _J = 125°C		320		10	
1	Diode Peak Reverse	I _F = 600A,	T _J = 25°C		450		^	
Irr	Recovery Current	Recovery Current di/dt=6500	di/dt=6500A/μs,	T _J = 125°C		590		Α
0	Diode Reverse Recovery	V _{rr} = 600V,	T _J = 25°C		56.5		nC	
Q _{rr}	Charge		T _J = 125°C		98.0			
E	Diode Reverse Recovery		T _J = 25°C		25.0		mJ	
E _{rr}	Energy		T _J = 125°C		37.5		1110	
$R_{ heta JC}$	Thermal Resistance, Junction-to-Case (Diode)					0.057	°C/W	

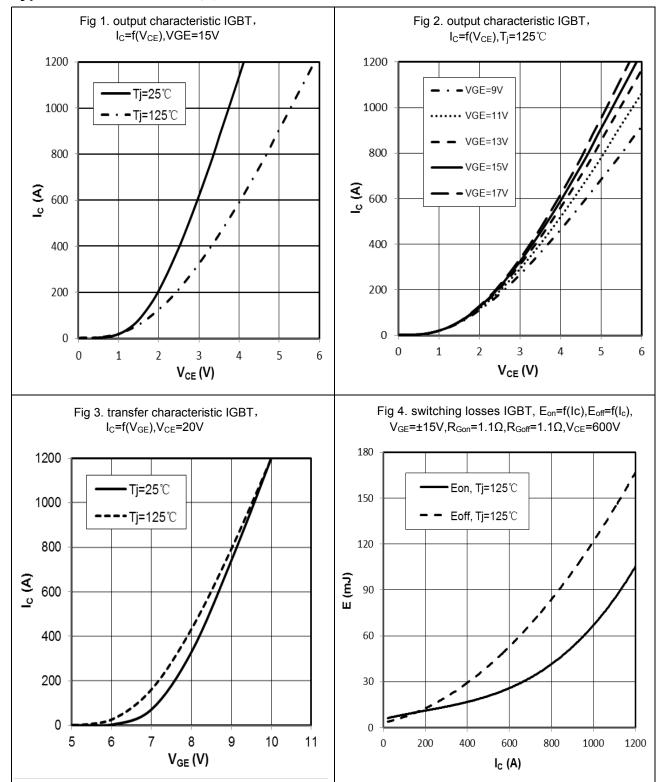
Absolute Maximum Ratings of Freewheeling Diode

Symbol	Parameter	Min.	Тур.	Max.	Units
V _{iso}	Isolation Voltage (All Terminals Shorted),f = 50Hz, 1minute	2500			V
$R_{\theta CS}$	Case-To-Sink(Conductive Grease Applied)		0.1		°C/W
M	Power Terminals Screw: M4	1.0		2.0	N·m
IVI	Power Terminals Screw: M6	3.0		5.0	N·m
М	Mounting Screw: M6	4.0		6.0	N·m
G	Weight		320		g

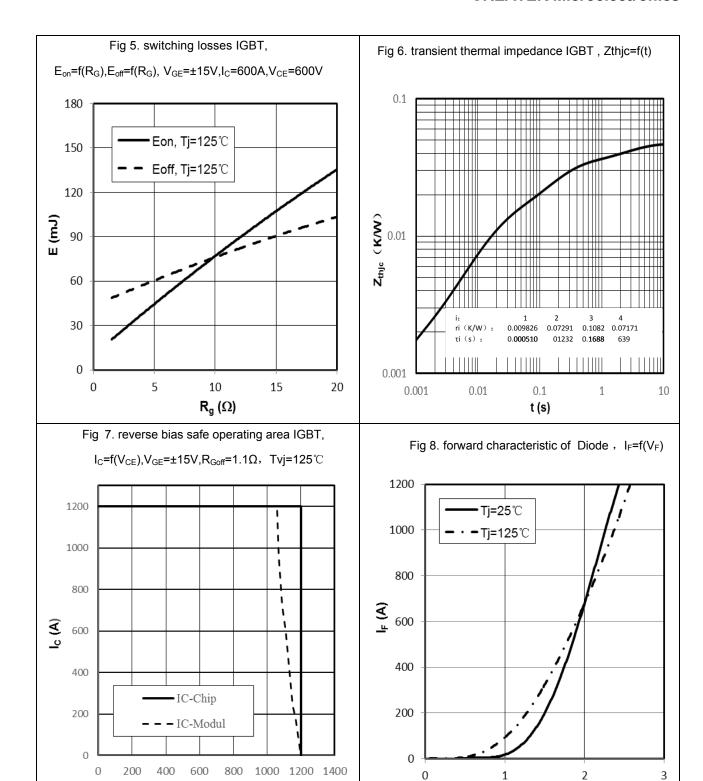
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Typical Characteristics (T_{amb} = 25 °C unless otherwise specified)



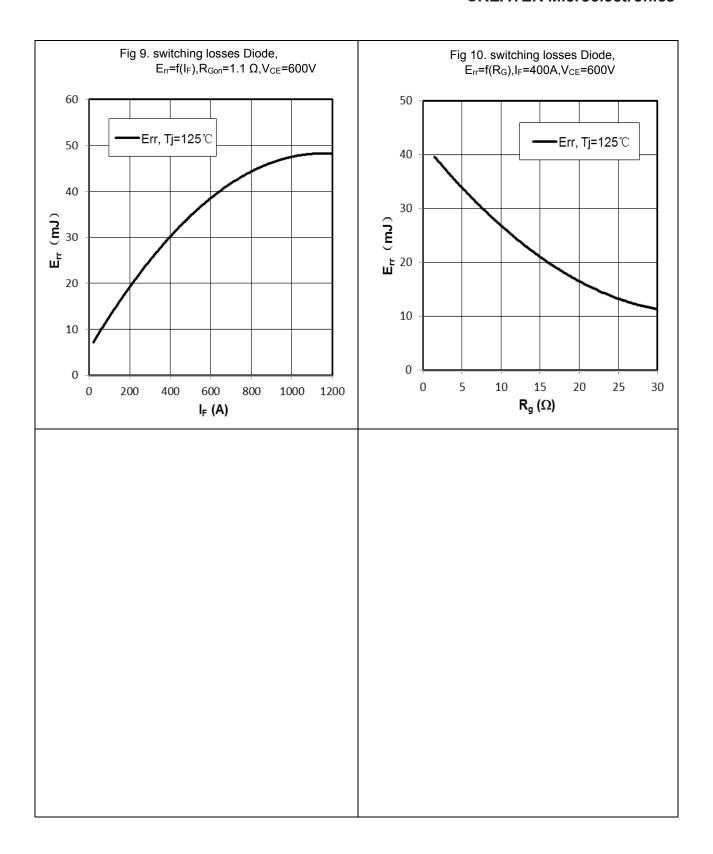




V_{CE} (V)

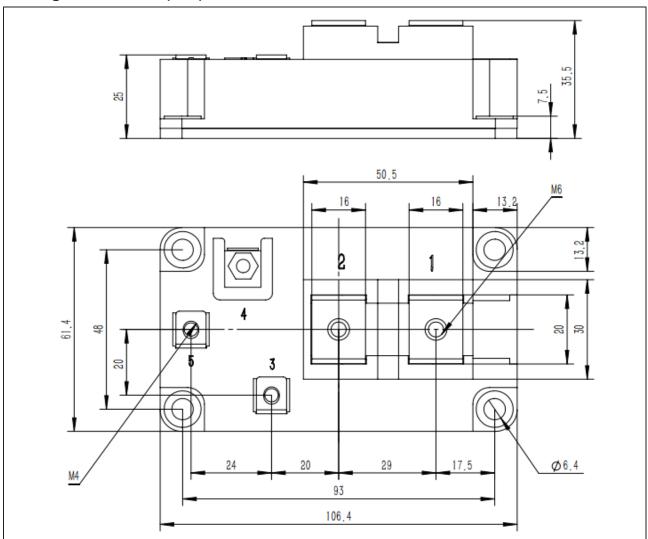
 $V_F(V)$







Package Dimensions(mm)



Ordering information

Order code	Package	Packaging option	Base quantity	Packaging specification
GPU600SG120D2	D2(62mm)	BOX	10pcs /BOX	

Revision history

Date	Revision	Changes
23-May-2016	1.0	Initial release
30-July-2018	2.0	Update

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